

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.54 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS			
I _{F(AV)}	2 x 10 A		
V_{RRM}	100 V		
I _{FSM}	120 A		
V _F at I _F = 10 A	0.65 V		
T _J max.	150 °C		
Package	TO-220AB		
Diode variations	Dual common cathode		

FEATURES

• Trench MOS Schottky technology

• Low forward voltage drop, low power losses

RoHS

• High efficiency operation

HALOGEN FREE

Solder dip 275 °C max. 10 s, per JESD 22-B106

 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V20100R	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	100	٧	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	20	А	
per diode		10		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	120	Α	
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	100 (minimum)	-	V	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _E (1)	0.62	-	V	
	I _F = 10 A			0.81	0.90		
	I _F = 5 A	T _A = 125 °C		V F (*)	0.54	-	\ \ \
	I _F = 10 A		1A = 125 C	0.65	0.72		
Reverse current per diode	V _R = 70 V	T _A = 25 °C	I _R ⁽²⁾	4	-	μA	
		T _A = 125 °C		4	-	mA	
	V _R = 100 V	T _A = 25 °C		-	150	μA	
		T _A = 125 °C		5.6	15	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V20100R	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.8	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V20100R-M3/4W	1.88	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

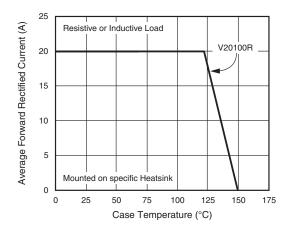


Fig. 1 - Maximum Forward Current Derating Curve

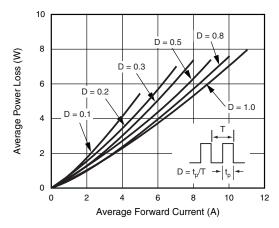


Fig. 2 - Forward Power Loss Characteristics Per Diode



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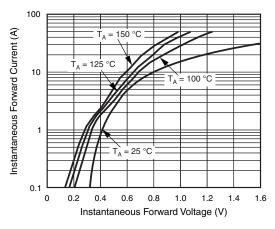


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

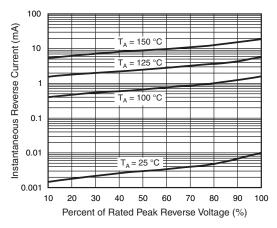


Fig. 4 - Typical Reverse Characteristics Per Diode

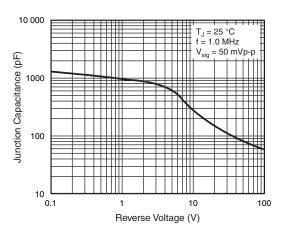


Fig. 5 - Typical Junction Capacitance Per Diode

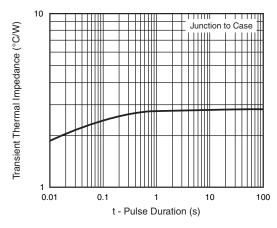
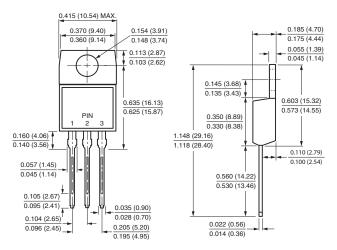


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB







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